NSN 5961-00-950-1655

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-950-1655
Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Internal Junction Configuration:
Pnp
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
-40.0 collector to base voltage, dc and -20.0 collector to emitter voltage/static/base open and -4.0 collector to emitter reverse voltage and
1.0 emitter to base voltage, dc
Current Rating Per Characteristic:
-10.00 milliamperes source cutoff current and 10.00 milliamperes source cutoff current blank
Power Rating Per Characteristic:
65.0 milliwatts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/267 government specification
Shelf Life:
N/a
Unit Of Measure:

Nic

Demilitarization:

NSN 5961-00-950-1655 Transistor - Page 2 of 2



Fiig:

A110a0